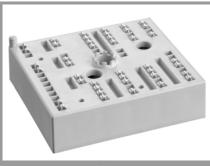
# SKIIP 24ACC12T4V1



### MiniSKiiP<sup>®</sup> 2

### **IGBT** module

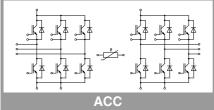
### SKiiP 24ACC12T4V1

### **Features**

- Trench 4 IGBTs
- ٠ Robust and soft freewheeling diodes in CAL technology
- · Highly reliable spring contacts for
- electrical connections • UL recognised: File no. E63532
- **Typical Applications\***
- 4Q inverters

### **Remarks**

- · Max. case temperature limited to T<sub>C</sub>=125°C
- · Product reliability results valid for T<sub>i</sub>≤150°C (recommended T<sub>j,op</sub>=-40...+150°C)
- · Terminal distances sufficient for basic insulation in 3-phase 480VAC TN systems
- DC-link voltage V<sub>DC</sub>≤800V
- Temperature sensor: no basic • insulation to main circuit, signal processing with reference to -DC potential
- Please refer to MiniSKiiP "Technical Explanations" and "Mounting Instructions" for further information
- Inverter IGBT=T1-T12
- Inverse Diode=D1-D12 •



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Absolute	Maximum Rating	S				
Symbol	Conditions		Values			Unit
Inverter -	IGBT					
V <sub>CES</sub>	T <sub>j</sub> = 25 °C	= 25 °C 1200			V	
Ic	λ <sub>paste</sub> =0.8 W/(mK)	T <sub>s</sub> = 25 °C		38		Α
	T <sub>j</sub> = 175 °C	T <sub>s</sub> = 70 °C		31		Α
I <sub>C</sub>	$\lambda_{paste}$ =2.5 W/(mK) T <sub>j</sub> = 175 °C	T <sub>s</sub> = 25 °C		43		Α
		T <sub>s</sub> = 70 °C		35		А
I <sub>Cnom</sub>			25		Α	
I <sub>CRM</sub>	$I_{CRM} = 3 \times I_{Cnom}$		75			Α
V <sub>GES</sub>				-20 20		V
t <sub>psc</sub>	$V_{CC} = 800 V$ $V_{GE} \le 15 V$ $V_{CES} \le 1200 V$	T <sub>j</sub> = 150 °C	10		μs	
Tj			-40 175		°C	
Inverse -	Diode					
I <sub>F</sub>	$\lambda_{paste}=0.8 \text{ W/(mK)}$ T <sub>j</sub> = 175 °C	T <sub>s</sub> = 25 °C		31		Α
		T <sub>s</sub> = 70 °C		25		Α
I <sub>F</sub>	$\lambda_{\text{paste}}=2.5 \text{ W/(mK)}$ T <sub>s</sub> = 25 °C 34			Α		
	T <sub>j</sub> = 175 °C	T <sub>s</sub> = 70 °C		27		Α
I <sub>Fnom</sub>			25		Α	
I <sub>FRM</sub>	I <sub>FRM</sub> = 2 x I <sub>Fnom</sub>		50			Α
I <sub>FSM</sub>	t <sub>p</sub> = 10 ms, sin 180°, T <sub>j</sub> = 150 °C		100			Α
Tj			-40 175		°C	
Module						
I <sub>t(RMS)</sub>	T <sub>terminal</sub> = 80 °C, 20	A per spring		40		Α
T <sub>stg</sub>			-40 125		°C	
V <sub>isol</sub>	AC sinus 50 Hz, t =	1 min	2500		V	
Characte	eristics					
Symbol	Conditions		min.	typ.	max.	Unit
Inverter -	IGBT					
V <sub>CE(sat)</sub>	I <sub>C</sub> = 25 A	T <sub>j</sub> = 25 °C		1.85	2.10	V
	V <sub>GE</sub> = 15 V chiplevel	T <sub>j</sub> = 150 °C		2.25	2.45	V

		.]	
	$du/dt = 3400 V/\mu s$	T 150.00	
	du/dt = 3400 V/μs V <sub>GE</sub> = +15/-15 V L <sub>s</sub> = 21 nH	T <sub>j</sub> = 150 °C	
	per IGBT, $\lambda_{paste}=0.8$	3 W/(mK)	
	per IGBT, $\lambda_{paste}$ =2.5	5 W/(mK)	
B	Rev 10-26022	010	

 $T_i = 25 °C$ 

T<sub>j</sub> = 150 °C

 $T_i = 25 °C$ 

T<sub>i</sub> = 150 °C

f = 1 MHz

f = 1 MHz

f = 1 MHz

T<sub>i</sub> = 150 °C

T<sub>i</sub> = 150 °C

T<sub>i</sub> = 150 °C

T<sub>j</sub> = 150 °C

0.80

0.70

42

62

5.8

0.1

1.43

0.12

0.09

142

0

39

32

3.2

333

91

3

1.13

0.94

5

0.90

0.80

48

66

6.5

0.3

V

V

 $m\Omega$ 

 $\mathsf{m}\Omega$ 

V

mA

nF

nF

nF

nC

Ω

ns

ns

mJ

ns

ns

mJ K/W

K/W

chiplevel

V<sub>GE</sub> = 15 V

 $V_{CE} = 25 V$ 

 $V_{GE} = 0 V$ 

T<sub>i</sub> = 25 °C

 $I_{\rm C} = 25 \, \text{A}$ 

V<sub>CC</sub> = 600 V

 $R_{G on} = 27 \Omega$ 

 $R_{G off} = 27 \ \Omega$ 

di/dt<sub>on</sub> = 780 A/µs

di/dt<sub>off</sub> = 360 A/μs T<sub>i</sub> = 150 °C

 $V_{GE} = V_{CE}, I_C = 1 \text{ mA}$ 

V<sub>GE</sub> = - 8 V...+ 15 V

V<sub>GE</sub> = 0 V, V<sub>CE</sub> = 1200 V, T<sub>i</sub> = 25 °C

chiplevel

V<sub>CE0</sub>

 $r_{CE}$ 

V<sub>GE(th)</sub>

ICES

Cies

Coes

Cres

 $Q_{G}$ 

R<sub>Gint</sub>

t<sub>d(on)</sub>

tr

tf

Eoff

R<sub>th(j-s)</sub>

 $R_{th(j-s)}$ 

 $\mathsf{E}_{\mathsf{on}}$ 

t<sub>d(off)</sub>



## MiniSKiiP<sup>®</sup> 2

### **IGBT** module

### SKiiP 24ACC12T4V1

### Features

- Trench 4 IGBTs
- Robust and soft freewheeling diodes in CAL technology
- Highly reliable spring contacts for
- electrical connectionsUL recognised: File no. E63532

### Typical Applications\*

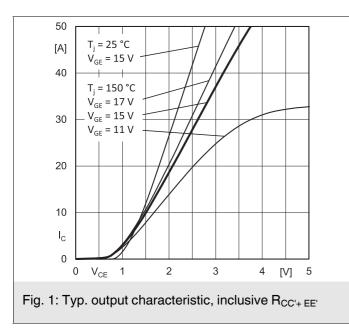
• 4Q inverters

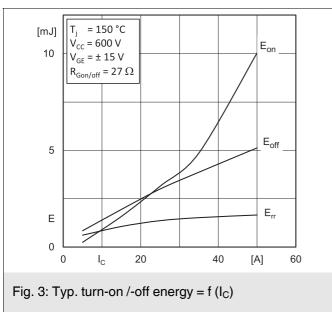
### Remarks

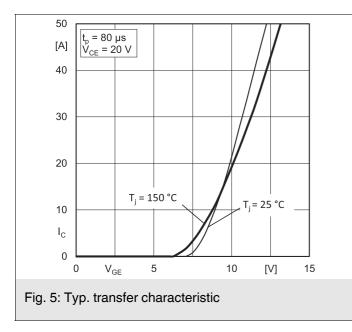
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- Product reliability results valid for  $T_j \le 150^{\circ}C$  (recommended  $T_{j,op}=-40...+150^{\circ}C$ )
- Terminal distances sufficient for basic insulation in 3-phase 480VAC TN systems
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- Inverter IGBT=T1-T12
- Inverse Diode=D1-D12

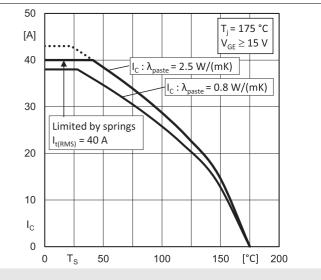
ACC			

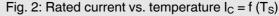
Characte	eristics					
Symbol	Conditions		min.	typ.	max.	Unit
Inverse -	Diode					
$V_F = V_{EC}$	I <sub>F</sub> = 25 A	T <sub>j</sub> = 25 °C		2.41	2.74	V
	V <sub>GE</sub> = 0 V chiplevel	T <sub>j</sub> = 150 °C		2.45	2.79	V
V <sub>F0</sub>	chiplevel	T <sub>j</sub> = 25 °C		1.30	1.50	V
		T <sub>j</sub> = 150 °C		0.90	1.10	V
r <sub>F</sub>	chiplevel	T <sub>j</sub> = 25 °C		44	50	mΩ
		T <sub>j</sub> = 150 °C		62	68	mΩ
I <sub>RRM</sub>	$-1V_{GF} = +15/-15V$	T <sub>j</sub> = 150 °C		23		Α
Q <sub>rr</sub>		T <sub>j</sub> = 150 °C		3.8		μC
E <sub>rr</sub>		T <sub>j</sub> = 150 °C		1.4		mJ
R <sub>th(j-s)</sub>	per Diode, $\lambda_{paste}$ =0.8 W/(mK)			1.6		K/W
R <sub>th(j-s)</sub>	per Diode, $\lambda_{\text{paste}}$ =2.5 W/(mK)			1.37		K/W
Module	·					
L <sub>CE</sub>				-		nH
Ms	to heat sink		2		2.5	Nm
w				55		g
Temperat	ure Sensor	<u>.</u>				
R <sub>100</sub>	T <sub>r</sub> =100°C (R <sub>25</sub> =1000Ω)			1670 ± 3%		Ω
R(T)	$R_{(T)}$ =1000Ω[1+A(T-25°C)+B(T-25°C) <sup>2</sup> ] , A = 7.635*10 <sup>-3</sup> C <sup>-1</sup> , B = 1.731*10 <sup>-5</sup> C <sup>-2</sup>					

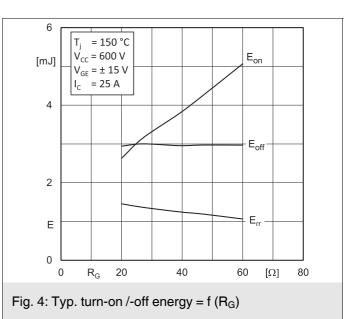


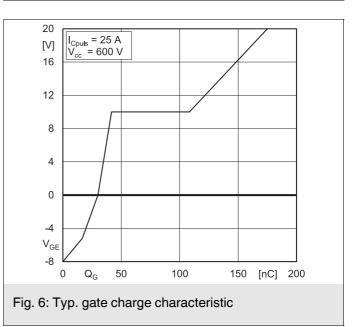


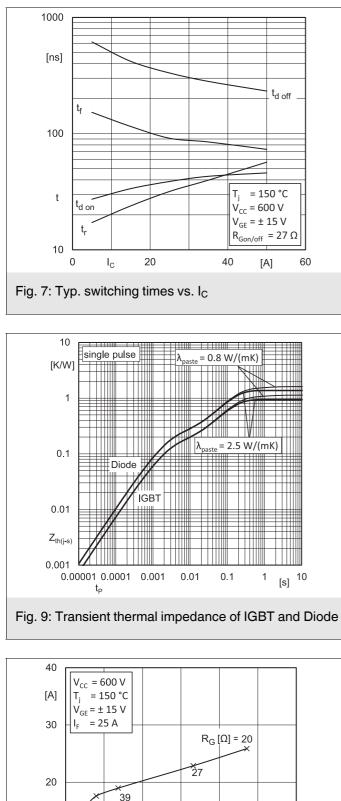


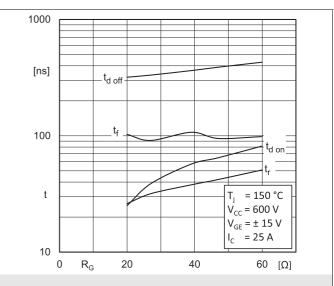


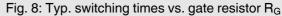


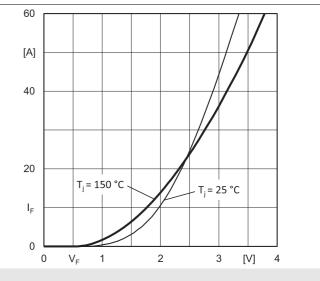


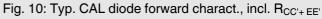


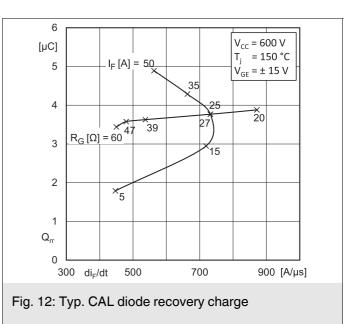


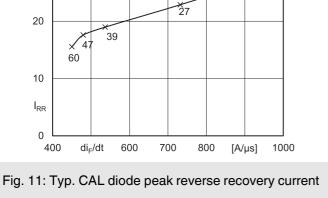


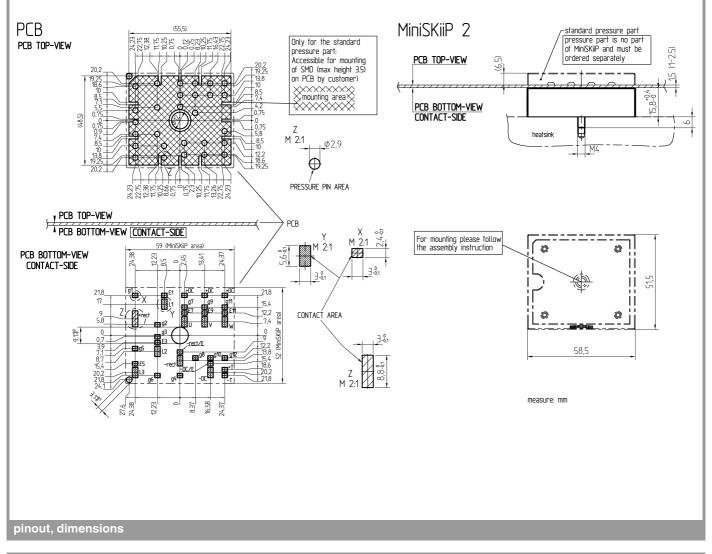


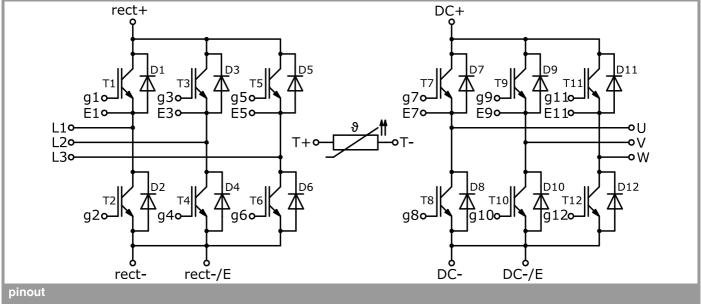












This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, chapter IX.

#### **\*IMPORTANT INFORMATION AND WARNINGS**

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